Effects of processing parameter on energy storage density and ferroelectric properties of lead-free bismuth sodium titanate-strontium bismuth titanate ceramics

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ABSTRACT: In order to clarify the optimal sintering conditions, the effects of processing parameter on phase evolution, physical, microstructure, dielectric, ferroelectric, and energy storage density properties of bismuth sodium titanate-strontium bismuth titanate ceramics (or BNT-SBT) were investigated. The studied ceramics were fabricated via a conventional mixed oxide method and sintered at temperatures ranging from 1100–1175 °C under normal atmosphere for 3 h dwell time with a heating/cooling rate of 5 °C/min. The XRD data revealed that the coexisting rhombohedral and tetragonal phases were observed in all of the ceramics. With increasing sintering temperature, the cubic-rich phase was dominated; and the average grain size tended to increase. For the ceramics sintered at 1150 °C, the good density (5.74 g/cm\textsuperscript{3}), dielectric ($\epsilon_{\text{max}} = 3510$, tan $\delta = 0.0501$, $T_{\text{F-R}} = 73.80 \degree\text{C}$, $T_{\text{m}} = 273 \degree\text{C}$), and ferroelectric ($P_r = 3.05 \mu\text{C/cm}^2$, $E_c = 7.69 \text{kV/cm}$) were obtained. In addition, the optimum sintering temperature of 1150 °C was also found to improve the energy storage density properties ($W = 0.94 \text{J/cm}^3$, $\eta = 89.93\%$ at 125 °C, and $E = E_{\text{max}}$).

KEYWORDS: sintering temperature, lead-free ceramics, dielectric and ferroelectric properties, energy storage density

INTRODUCTION

Materials with high energy storage density ($W$) and high energy storage efficiency ($\eta$) are desired to meet the growing requirements for compact electrics and devices \cite{1, 2}. Among the various electrical energy storage materials, dielectric ceramics are widely studied for their excellent energy storage performance \cite{3}. Ceramic-based dielectric capacitors have drawn growing interest due to their small volume, excellent thermal properties, good mechanical properties, fast charge-discharge speed, and high-power density \cite{4}. Besides, large maximum polarization ($P_{\text{max}}$) and low remnant polarization ($P_r$) in the relaxor ferroelectrics are key features for $W$ and $\eta$ in the selection of materials \cite{5}.

The bismuth sodium titanate (Bi$_{0.5}$Na$_{0.5}$TiO$_3$ or BNT) has been identified as a potential energy storage material because it has a large spontaneous polarization ($P_s$) over 40 $\mu\text{C/cm}^2$ \cite{6}, which originates from the hybridization of Bi 6p and O 2p orbitals \cite{4}. However, the BNT has large $P_r$ at ambient temperature and high coercive field ($E_c \sim 73 \text{kV/cm}$) \cite{6, 7}, which limit its energy storage density resulting in a small recoverable energy storage density ($W_{\text{rec}}$) and a low $\eta$ values \cite{4, 8, 9}. The BNT-based ceramics have also been widely used in the energy-storage devices because their permittivity and polarization are higher than other linear dielectrics \cite{10}. For the sake of promoting the energy storage properties with decreasing $P_r$ value, the modulation of BNT by other perovskite compositions was identified \cite{9}.
Strontium bismuth titanate (Sr$_{0.7}$Bi$_{0.2}$TiO$_3$ or SBT) is a relaxor ferroelectric with perovskite structure, which possesses several advantages for energy storage [11]. SBT ceramics exhibit good relaxor ferroelectric behavior and a diffused dielectric maximum in a wide range of temperatures, resulting from the Sr site vacancy and the off-centered Bi$^{3+}$ ion [11]. The SBT ceramics show relaxation behavior, which is essentially caused by the dipolar interaction [12]. Qiao et al [4] studied the energy density and thermal stability properties of relaxor ferroelectric BNT-SBT ceramics. In their study, the SBT was introduced into the BNT ceramic via a standard solid-state route to modulate its relaxation behavior and energy storage performance. With increasing SBT content, the perovskite structure of BNT transformed from a rhombohedral phase to a weakly polarized pseudo-cubic phase, and the relaxation behavior was enhanced. In particular, the dielectric breakdown strength ($E_{\text{DBS}}$) improved from 120 kV/cm (of the pure BNT ceramic) to around 160 kV/cm (of the 0.6BNT-0.4SBT ceramic), which displayed a large $W_{\text{rec}}$ of 2.20 J/cm$^3$, implying a large potential ability of the 0.6BNT-0.4SBT ceramic in energy storage [4]. Li et al [5] also found a significant increase of $W$ (1.5 J/cm$^3$) and $\eta$ (73%) for the BNT-SBT ergodic relaxor (ER) ceramics. The significant increase of $W$ was due to the ceramics’ low $P_t$ and large $P_{\text{max}}$, which were induced by adding SBT into the (1-x)Bi$_{0.5}$Na$_{0.5}$TiO$_3$-(xSr$_{0.85}$Bi$_{0.15}$)$_3$TiO$_3$ ceramic. Ang and Yu [13] have also reported that the BNT-SBT relaxor ferroelectrics exhibit a very high ferroelectric polarization and a high purely electrostrictive strain. Therefore, it can be reasonably expected that the ER state, with low $P_t$, combined with large $P_{\text{max}}$ induced by SBT-doping BNT ceramics, might improve the energy-storage properties of the BNT-SBT ceramics.

According to the above study reports, it could say that the SBT plays an important role in improving the $W_{\text{rec}}$ of BNT-based system. In the present study, we selected the BNT with excellent piezoelectric as base material, and a small amount of SBT was added as additive at the composition of 0.7BNT-0.3SBT ceramics (which showed interesting electrical properties, i.e., the $W$) [4, 10]. Moreover, as sintering process is important for fabrication of ceramic materials [14], the effects of sintering temperatures on the densification, phase, microstructure, dielectric, ferroelectric, and $W$ were investigated and discussed in details. It was expected that the optimum sintering condition could produce ceramics with better properties.

**MATERIALS AND METHODS**

The lead-free 0.7BNT-0.3SBT ceramic was prepared by the conventional mixed-oxide method. Analytical grade reagents of Bi$_2$O$_3$, Na$_2$CO$_3$, TiO$_2$, and SrCO$_3$ were used as the starting raw materials. All carbonate powders were dried at 120 °C for 24 h to remove any moisture. The 0.7BNT-0.3SBT obtained was stoichiometrically weighed and mixed by ball milling in 99.9% ethanol for 24 h, and the slurry was dried in an oven. The resulted mixed powder was calcined in air atmosphere at 850 °C for 3 h dwell time. A few drops of 4 wt% polyvinyl alcohol binders were added to the mixed powder, which was then uniaxially pressed into disc pellets (10 mm in diameter and about 1.2 mm in thickness), or the ceramics, to be used as ceramic samples. The ceramics were sintered at 1100, 1125, 1150, and 1175 °C for 3 h dwell time with a heating/cooling rate of 5 °C/min in closed alumina crucibles.

Bulk density was measured with Archimedes’ method. An X-ray diffractometer (XRD, PANalytical, X’ Pert Pro MPD) was used to study the microstructure of the ceramics. The grain size of the ceramics was measured using the linear intercept method. Before performing the electrical measurements, all the ceramic samples had been polished into a parallel surface with 1 mm thickness. Silver paste was painted onto both sides of the pellet. Then, the samples were heated at 700 °C for 15 min to form electrodes. For electrical characterizations, dielectric properties as a function of temperature (25–500 °C) were determined using an LCR-meter (HP model 4192A) at frequencies ranging from 1 to 1000 kHz. A ferroelectric system based on Radiant Precision High Voltage Interface was used to measure the polarization-electric field ($P$-$E$) hysteresis loops at both room temperature (RT) and high temperature (HT) of 25–150 °C. A maximum electric field of 50 kV/cm and a frequency of 1 Hz were applied to each sample. $P_t$, $P_{\text{max}}$, and $E_c$ values were determined from the hysteresis loops. By using data from ferroelectric properties, $W$, $W_{\text{loss}}$, and $\eta$ values were also calculated.

**RESULTS AND DISCUSSION**

**Densification, phase formation, and microstructure**

The densification of all ceramics sintered at various sintering temperatures from 1100–1175 °C are listed in Table 1. The data clearly showed that the
Table 1  Physical, phase, microstructure, and electrical properties of 0.7BNT-0.3SBT ceramics sintered at various temperatures.

| Sintering temp. (°C) | Density (g/cm³) | c/a | Grain size (µm) | T_{FR} (°C) | T_{m} (°C) | ϵ_{max} (@1 kHz) | tan δ (@1 kHz) | P_{r}^{a} (µC/cm²) | E_{c}^{a} (kV/cm) | P_{r}^{b} (µC/cm²) | E_{c}^{b} (kV/cm) |
|---------------------|-----------------|-----|----------------|-------------|------------|-----------------|----------------|----------------|----------------|----------------|----------------|------------------|
| 1100                | 5.68            | 1.0100 | 1.28           | 81.12       | 278        | 3249            | 0.0566         | 2.47            | 5.71           | 1.69           | 0.69           |
| 1125                | 5.71            | 1.0094 | 1.54           | 74.61       | 275        | 3320            | 0.0396         | 2.84            | 5.77           | 1.14           | 1.75           |
| 1150                | 5.74            | 1.0084 | 2.02           | 73.80       | 273        | 3510            | 0.0501         | 3.05            | 7.69           | 0.86           | 3.49           |
| 1175                | 5.61            | 1.0076 | 2.51           | 70.61       | 271        | 2921            | 0.0388         | 3.62            | 10.9           | 1.30           | 4.48           |

a Data obtained at RT and electric field of 50 kV/cm.

b Data obtained at 125 °C and electric field of 50 kV/cm.

Fig. 1 X-ray diffraction patterns of 0.7BNT-0.3SBT ceramics sintered at various sintering temperatures: (a) 2θ = 20–70°, (b) 2θ = 39–41°, and (c) 2θ = 45–48°.

density was improved by the increase of sintering temperature, and a maximum value of 5.74 g/cm³ was obtained for the ceramics sintered at 1150 °C. The density was slightly decreased to the minimum value of 5.61 g/cm³ when the sintering temperature increased to 1175 °C. The reason for the decrease of density value at high temperature was likely due to the evaporation of volatile alkali metal oxides and partial melting at high temperature [15]. In addition, at sintering temperatures lower than 1100 °C, the pellet ceramic samples could not form a ceramic (not dense). Besides, it was found that at high sintering temperature over 1175 °C (such as 1200 °C), the ceramic started to melt and agglomerated with the covered powders into a hard irregular shape object. Thus, the ceramics sintered at < 1100°C and > 1175°C were excluded from further electrical investigation.

Fig. 1(a) shows the X-ray diffraction patterns of the 0.7BNT-0.3SBT ceramics sintered at various sintering temperatures where 2θ = 20–70°. For the analysis of phase transition process, the XRD patterns for selected narrow angular ranges of 2θ = 39–41° and 2θ = 45–48° are presented in Fig. 1(b) and (c), respectively. Within the resolution limit of XRD, all sintered ceramics exhibited a single phase of perovskite structure and no secondary phase could be observed, indicating that SBT completely diffused into the host lattice of BNT [4]. It was possible that a solid solution between BNT and SBT was formed. This was because when the solid solution was made, Sr ions could replace Bi and Na ions, as the ionic radius of Sr ions (1.44 Å) is not much different from the radii of Bi (1.40 Å) and Na (1.39 Å) ions (percentage of the difference is 2.86–3.59%). Moreover, the solubility limit of SBT in BNT lattice was believed to be more than 30 mol% because no trace of secondary phases was detected in XRD patterns. All sintered ceramics had a mixed phase of rhombohedral and tetragonal, as evidenced by a slight splitting of rhombohedral {111} reflections at 2θ = 39–41° and tetragonal {200} reflections at 2θ = 45–48° [16]. However, sintering temperatures had slight effects on the phase evolution. With increasing sintering temperatures, the cubic-rich phase was dominated. This behavior became clearer after the calculated lattice parameters (a and c) had been analyses, which indicated a decrease in tetragonality (c/a) (see Table 1).

In this study, scanning electron microscope (SEM) was used to determine the morphologies of all the ceramics. The grain size of the ceramics was measured and calculated based on a mean linear interception method. SEM micrographs, with as-sintered surface mode of the 0.7BNT-0.3SBT ceramic sintered at various sintering temperatures, are shown in Fig. 2. The average grain size values are also summarized in Table 1. It could be seen that the ceramics’ grains displayed well crystallized cubic-like shape with clear boundaries. The grain sizes increased with increasing sintering temperatures, from 1.28 µm for the 1100 °C ceramic to around 2.51 µm for the 1175 °C ceramic. This behavior was in good agreement with other previously reported
BNT-based ceramics [16, 17], and the reasons for the grain growth could be caused by a mass transfer at grain boundaries and the enhanced diffusion rate by raising sintering temperature [18].

**Dielectric properties**

Dielectric constant ($\epsilon_r$) and dielectric loss ($\tan\delta$) can be used to analyse not only the ferroelectric relaxation properties, but also the phase structure changes by the anomalous points of dielectric curves [19]. Fig. 3 shows temperature dependence on $\epsilon_r$ and $\tan\delta$ of the poled 0.7BNT-0.3SBT ceramics sintered at various sintering temperatures and measured at various frequencies (from 1-1000 kHz). In BNT-based materials, two distinctive dielectric anomalies are always discerned [17]. In this study, the result showed that all the ceramic samples also existed at two dielectric peaks referred to as $T_{FE}$ and $T_m$, respectively. The first dielectric anomaly, which involved a frequency dependent dielectric permittivity, and the changes in loss tangent illustrated the relaxor ferroelectrics characteristics [20]. Normally, the lower anomaly peak is located near $T_{FE}$, which is known as the ferroelectric (FE) to ergodic (ER) phase transition temperature [21]. The high temperature anomaly peak is called $T_m$, where the dielectric constant reaches its maximum value [22, 23]. The sintering temperature has effects on the $T_{FE}$, $T_m$ and $\epsilon_{max}$ values. Fig. 4(a) shows that the ceramics sintered 1100 °C had $T_{FE}$ and $T_m$ values of 81.12 °C and 278 °C, respectively. Both $T_{FE}$ and $T_m$ values decreased with increasing sintering temperatures. The downward shift of $T_{FE}$ with increasing sintering temperatures could be a consequence of ferroelectric order destabilization associated with the possible presence of ergodic relaxor (ER) phase in the ceramics [24]. From Fig. 4(b), the ceramic sintered at 1100 °C had maximum dielectric constant ($\epsilon_{max}$) of 3249. The $\epsilon_{max}$ increased with increasing sintering temperatures and reached the maximum value of 3510 at 1150 °C. The value was slightly decreased when the sintering temperature was at 1175 °C. Thus, the $\epsilon_{max}$ of the ceramics could be improved by increasing the sintering temperature in this system. Normally, electrical properties of many ferroelectric materials can be influenced by many factors including grain size and density. For the grain size effect, it is known that the grain boundary is a low-permittivity region. When the grain size increases, the grain boundary decreases; thus, dielectric constant increases [25]. However, in the present study, the $\epsilon_{max}$ of the 1175 °C ceramic was less than that of the 1150 °C. Thus, the grain size might not be the main factor affecting the dielectric constant (see inset of Fig. 4(b)). Moreover, it was found that the density of the ceramics exhibited the same trend as the $\epsilon_{max}$. Therefore, it is believed that the density should be the main factor that affects the dielectric constant. Similar observation in the BNKST ceramics was found by Tho et al [26] who reported that $\epsilon_{max}$ increased with increasing sintering temperatures, and the highest $\epsilon_{max}$ was obtained at 1100 °C, with maximum density of 5.88 g/cm³.

**Ferroelectric and energy storage density analysis**

The effects of sintering temperatures on polarization-electric field ($P-E$) hysteresis loop of the 0.7BNT-0.3SBT ceramics were investigated. Fig. 5 shows $P-E$ hysteresis loop of the ceramic sintered at various sintering temperatures, measured at room temperature under an electric field of 50 kV/cm and a frequency of 1 Hz. The results showed that sintering temperatures had a slight influence on the ferroelectric hysteresis loop shape. However, details of the $P_E$ and $E_c$ are listed in Table 1. All of the ceramics exhibited a pinching in the $P-E$ hysteresis loop at room temperature (RT), which indicated the presence of a mixture of ferroelectric (FE) and ergodic relaxor (ER) phases [27]. It should be noted that the 1150 °C exhibited a more pronounced pinched loop with low $P_E$. This indicated that the composition of the ceramic samples had higher amount of ER phases. At a low sintering temperature of 1100 °C, the minimum $P_E$ of 2.47 μC/cm² and $E_c$ of 5.71 kV/cm were observed. The $P_E$ and $E_c$ values increased with increasing sintering temperatures.
Fig. 3 Temperature dependence on dielectric constant ($\epsilon_r$) and dielectric loss (tan $\delta$) of poled 0.7BNT-0.3SBT ceramics sintered at various sintering temperatures, measured at various frequencies from 1–1000 kHz: (a) 1100 °C, (b) 1125 °C, (c) 1150 °C, and (d) 1175 °C.

Fig. 4 Plots of (a) $T_{P,E}$ and $T_m$ @1 kHz as a function of sintering temperatures and (b) $\epsilon_{\text{max}}$ @1 kHz and density values as a function of sintering temperatures of 0.7BNT-0.3SBT ceramics sintered at various sintering temperatures (inset: grain sizes as a function of sintering temperatures).

temperatures and respectively showed the maximum value of 3.62 $\mu$C/cm$^2$ and 10.90 kV/cm for the 1175 °C ceramic. The increasing $P_r$ value in this study could be due to the increasing grain size caused by the sintering temperature. Normally, the
Temperature dependence on polarization-electric field (P-E) hysteresis loops of 0.7BNT-0.3SBT ceramics sintered at various sintering temperatures, measured under an electric field of 50 kV/cm and a frequency of 1 Hz.

A grain boundary is a low-permittivity region. That means the grain boundary has poor ferroelectricity. The number of grain boundary decreases as grain size increases, thus, \( P_r \) value increases \(^{[25]}\). Similar results were observed in the Ba\(_{0.8}\)Sr\(_{0.2}\)TiO\(_3\) ceramics studied by Mudinepalli et al \(^{[25]}\) who found that the \( P_r \) increased with increasing grain size and sintering temperature. Tan et al \(^{[28]}\) also found the \( P_{\text{max}} \) and \( P_r \) slightly increased with increasing grain size for BaTiO\(_3\) ceramic prepared by spark plasma sintering method (SPS).

Temperature dependence on polarization-electric field (P-E) hysteresis loops of the 0.7BNT-0.3SBT ceramics sintered at various sintering temperatures, measured under an electric field of 50 kV/cm and a frequency of 1 Hz are depicted in Fig. 6. All 0.7BNT-0.3SBT ceramics already exhibited ergodic relaxor (ER) characteristic at RT. When the temperature increased, the P-E hysteresis loops became more pinched, confirming that the ferroelectric to relaxor phase transition was induced by thermal activation, thus leaving an ergodic relaxor (ER) state at zero electric field \(^{[29]}\). The drastic decrease in both \( P_r \) and \( E_c \) values might also be related to the onset of strong ergodicity \(^{[30]}\).

As a rule, the pinched P-E loop is always good for improving recoverable energy storage density in dielectric materials \(^{[4]}\). To evaluate the practicability of these ceramics for energy storage systems, the energy storage density (\( W \)) and energy storage efficiencies (\( \eta \)) of the studied ceramics were calculated from the P-E loops using the following equations \(^{[4,31,32]}\):

\[
W = \int_{P_r}^{P_{\text{max}}} E \, dP, 
\]

\[
\eta = \frac{W}{W - W_{\text{loss}}} \times 100, 
\]

where \( E \) is the electric field, \( P \) is the polarization, \( P_{\text{max}} \) is the maximum polarization, \( P_r \) is the remnant polarization, and energy loss density is denoted as \( W_{\text{loss}} \) \(^{[4,31,32]}\). In this study, the schematics calculation of \( W \) and \( W_{\text{loss}} \) values could be obtained from Fig. 7(a). Plots of \( W \) and \( \eta \) values as a function of the temperatures (at \( E = 50 \) kV/cm) of all studied ceramics are shown in Fig. 7(b) and Fig. 7(c), respectively. The related energy storage values are also summarized in Table 2. The \( W \) and \( \eta \) values of all ceramics increased with increasing sintering temperature.

\[
\begin{array}{cccccc}
\text{Sintering} & \text{\( W^a \)} & \eta^a & \text{\( W^b \)} & \eta^b & \text{\( W^c \)} & \eta^c \\
\text{temp. (°C)} & \text{(J/cm\textsuperscript{2})} & \text{(%)} & \text{(J/cm\textsuperscript{2})} & \text{(%)} & \text{(J/cm\textsuperscript{2})} & \text{(%)} \\
1100 & 0.28 & 54.81 & 0.38 & 71.02 & 0.82 & 81.21 \\
1125 & 0.31 & 53.83 & 0.44 & 76.59 & 0.83 & 84.11 \\
1150 & 0.32 & 52.91 & 0.44 & 72.51 & 0.94 & 89.93 \\
1175 & 0.28 & 46.61 & 0.39 & 67.03 & 0.86 & 87.90 \\
\end{array}
\]

\(^a\) Data obtained at RT and electric field of 50 kV/cm.
\(^b\) Data obtained at 125 °C and electric field of 50 kV/cm.
\(^c\) Data obtained at 125 °C and the maximum electric field.
temperatures from RT (25 °C) to HT (150 °C) (see Fig. 7(b) and Fig. 7(c)). At the applied electric field of 50 kV/cm and at RT, the W and η values increased with increasing sintering temperatures and respectively reached the maximum values of 0.32 J/cm³ and 52.91% at 1150 °C. At the higher sintering temperature of 1175 °C, the W and η values slightly decreased.

Similarly, at the applied electric field of 50 kV/cm and at 125 °C, the W and η values of the ceramics increased with increasing sintering temperatures and respectively reached the maximum values of 0.44 J/cm³ and 71.51% at 1150 °C. In addition, plots of the W values obtained at 125 °C as a function of the electric field (until breakdown strength was reached) are shown in Fig. 7(d). At the maximum electric field and 125 °C, the ceramic sintered at 1150 °C showed the maximum values of W and η of 0.94 J/cm³ and 89.93%, respectively. Yu et al [33] have pointed out that grain size is a factor that affects the W value. However, the reason for the improvement of W of the 1150 °C ceramics in this study was likely due to the lower P, value when compared with those of other samples (Table 1); and the lower P, value could be a result of the higher ER phase.

Based on our results, it could be suggested that the optimum sintering temperature for preparing ceramics with high density and electrical properties, i.e. dielectric and energy storage density, was 1150 °C, and the 1150 °C ceramic could be considered as one of promising candidate materials for the production of high energy density devices.

CONCLUSION

In this study, the 0.7Bi₀.₅Na₀.₅TiO₃-0.3Sr₀.₇Bi₀.₂TiO₃, or 0.7BNT-0.3SBT, ceramics sintered at various sintering temperatures were successfully synthesized by a conventional mixed oxide method. The processing sintering temperature had a strong effect on microstructure, dielectric, ferroelectric, and energy storage density properties of the ceramics. The optimum sintering temperature for preparing ceramics with high densification and electrical performance was 1150 °C. Grain size values increased with increasing sintering temperature. The ceramic sintered at 1150 °C showed good densification (bulk density = 5.74 g/cm³), dielectric (ε_max = 3510, tan δ = 0.0501, T_ER = 73.80 °C, T_m = 273°C), ferroelectric (P_s = 3.05 μC/cm², E_c = 7.69 kV/cm), and energy storage properties (W = 0.94 J/cm³, η = 89.93% at 125 °C and maximum electric field). Based on our results, the sintering temperature for preparing ceramics with high density and high electrical and energy storage density properties was 1150 °C.

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REFERENCES

temperature stability of (1-x)(0.65Bi$_{0.5}$Na$_{0.5}$TiO$_3$ -0.35Bi$_{0.5}$Sr$_{0.5}$TiO$_3$)-xNbO$_3$ ceramics. Ceram Int 44, 10968–10974.


16. Dung DD, Quyet NV, Bac LH (2015) Role of sintering temperature on giant fieldinduced strain in lead-free Bi$_{0.5}$(NaK)$_{0.5}$TiO$_3$-based ceramics. Ferroelectrics 474, 113–119.

17. Bac DLH, Hong HS, Odkhuu D, Dung DD (2016) Effect of sintering temperature on properties of lead-free piezoelectric 0.975Bi$_{0.5}$(Na$_{0.92}$K$_{0.18}$)$_{0.5}$TiO$_3$-0.025LiTaO$_3$ ceramics. J Nanosci Nanotechnol 16, 7299–7934.


19. Zhao N, Fan H, Ma J, Ren X, Shi Y, Zhou Y (2018) Large strain of temperature insensitive in (1-x)(0.94Bi$_{0.5}$Na$_{0.5}$TiO$_3$-0.06BaTiO$_3$)-xSr$_{0.5}$La$_{0.5}$TiO$_3$ lead-free ceramics. Ceram Int 44, 11331–11339.


21. Ge RF, Zhao ZH, Duan SF, Kang XY, Lv YK, Yin DS, Dai Y (2017) Large electro-strain response of La$^{3+}$ and Nb$^{5+}$ co-doped ternary 0.85Bi$_{0.5}$Na$_{0.5}$TiO$_3$-0.11Bi$_{0.5}$K$_{0.5}$TiO$_3$-0.04BaTiO$_3$ lead-free piezoelectric ceramics. J Alloys Compd 724, 1000–1006.

22. Lv YK, Duan SF, Zhao ZH, Kang XY, Ge RF, Wang H, Dai Y (2018) Enhanced electromechanical strain response in (Fe$_{0.5}$Nb$_{0.5}$)$_{4+}$-modified Bi$_{0.5}$(Na$_{0.8}$K$_{0.2}$)$_{0.5}$TiO$_3$ lead-free piezoelectric ceramics. J Mater Sci 53, 8059–8066.


24. Hao J, Xu Z, Chu R, Li W, Fu P, Du J, Li G (2016) Structure evolution and electrostrictive properties in (Bi$_{0.5}$Na$_{0.5}$)$_{0.94}$Ba$_{0.06}$TiO$_3$-M$_2$O$_5$ (M = Nb, Ta, Sb) lead-free piezoceramics. J Eur Ceram Soc 36, 4003–4014.


26. Tho NT, Vuong LD (2020) Effect of sintering temperature on the dielectric, ferroelectric and energy storage properties of SnO$_2$-doped Bi$_{0.5}$(Na$_{0.84}$K$_{0.16}$)$_{0.5}$TiO$_3$ lead-free ceramics. J Adv Ceram 4, ID 2050011.


31. Zhao Y, Xu J, Yang L, Zhou C, Lu X, Yuan C, Li Q, Chen G, et al (2016) High energy storage property and breakdown strength of Bi$_{0.5}$(Na$_{0.82}$K$_{0.18}$)$_{0.5}$TiO$_3$ ceramics modified by (Al$_{0.5}$Nb$_{0.5}$)$_{4+}$ complexation. J Alloys Compd 666, 209–216.

32. Hu B, Fan H, Ning L, Wen Y, Wang C (2018) High energy storage performance of [(Bi$_{0.5}$Na$_{0.5}$)$_{0.5}$Ba$_{0.06}$]-0.97La$_{0.5}$Ti$_{1.2}$(Al$_{0.5}$Nb$_{0.5}$)$_{0.5}$O$_2$ ceramics with enhanced dielectric breakdown strength. Ceram Int 44, 15160–15166.